Vishay High Power Products

Medium Power Thyristors (Stud Version), 25 A

FEATURES

- Improved glass passivation for high reliability and exceptional stability at high temperature
- High dl/dt and dV/dt capabilities
- Standard package
- Low thermal resistance
- Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- · RoHS compliant
- Designed and qualified for industrial and consumer level

TYPICAL APPLICATIONS

- Medium power switching
- Phase control applications
- Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I		25	A			
I _{T(AV)}	T _C	85	°C			
I _{T(RMS)}		40	А			
	50 Hz	420	A			
I _{TSM}	60 Hz	440				
² t	50 Hz	867	A ² s			
1-1	60 Hz	790	A-5			
V _{DRM} /V _{RRM}		100 to 1200	V			
t _q	Typical	110	μs			
TJ		- 65 to 125	°C			

TO-208AA (TO-48)

25 A



ROHS COMPLIANT

PRODUCT SUMMARY

I_{T(AV)}

25RIA Series

Vishay High Power Products Medium Power Thyristors (Stud Version), 25 A



ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA		
	10	100	150	20		
	20	200	300			
	40	400	500			
25RIA	60	600	700	10		
	80	800	900	10		
	100	1000	1100			
	120	1200	1300			

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/µs

 $^{(2)}\,$ For voltage pulses with $t_p \leq 5\mbox{ ms}$

PARAMETER	SYMBOL		TEST CONDI	TIONS	VALUES	UNITS
Maximum average on-state current at case temperature	I _{T(AV)}	180° sinus	oidal conductior	1	25 85	A °C
Maximum RMS on-state current	I _{T(RMS)}				40	А
		t = 10 ms	No voltage		420	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		440	٨
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal	350	A
		t = 8.3 ms	reapplied	half wave,	370	
		t = 10 ms	No voltage	initial T _J =	867	
Maximum I ² t for fusing	l ² t	t = 8.3 ms	t = 8.3 ms reapplied	T _J maximum	790	A ² s
		t = 10 ms	100 /0 VRRM		615	
		t = 8.3 ms			560	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		8670	A²√s	
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x I _{T(AV)} < I < π x I _{T(AV)}), T _J = T _J maximum		0.99	V	
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(A)})$	(V)), $T_J = T_J \max$	timum	1.40	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), T _J = T _J maximum		10.1	mΩ	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J maximum$		5.7	1115.2	
Maximum on-state voltage	V _{TM}	I _{pk} = 79 A,	T _J = 25 °C		1.70	V
Maximum holding current	I _H	т об ос	anada aunatu (130	~^^
Latching current	١L	T_J = 25 °C, anode supply 6 V, resistive load		200	mA	



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SWITCHING					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
$V_{DRM} \le 600 \text{ V}$				200	
Maximum rate of rise	$V_{DRM} \le 800 V$	dl/dt	$T_J = T_J$ maximum, V_{DM} = Rated V_{DRM} Gate pulse = 20 V, 15 Ω , t_p = 6 µs, t_r = 0.1 µs maximum – I_{TM} = (2 x rated dl/dt) A	180	A/µs
	$V_{DRM} \leq 1000 \ V$	ai/at		160	
	$V_{DRM} \le 1600 \ V$			150	
Typical turn-on time		t _{gt}	T _J = 25 °C, at rated V _{DRM} /V _{RRM} , T _J = 125 °C	0.9	
Typical reverse recovery time		t _{rr}	$\label{eq:T_J} \begin{split} T_J &= T_J \text{ maximum}, \\ I_{TM} &= I_{T(AV)}, t_p > 200 \ \mu\text{s}, \ dl/dt = -10 \ \text{A}/\mu\text{s} \end{split}$	4	μs
Typical turn-off time		tq	$\label{eq:tau} \begin{split} T_J = T_J \; maximum, \; I_{TM} = I_{T(AV)}, \; t_p > 200 \; \mu s, \; V_R = 100 \; V, \\ dI/dt = - \; 10 \; A/\mu s, \; dV/dt = 20 \; V/\mu s \; linear \; to \; 67 \; \% \; V_{DRM}, \\ gate \; bias \; 0 \; V \; to \; 100 \; W \end{split}$	110	

Note

+ $t_q = 10 \ \mu s$ up to 600 V, $t_q = 30 \ \mu s$ up to 1600 V available on special request

BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum critical rate of rise	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	100	W/ue	
of off-state voltage	uv/ui	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	300 (1)	V/µs	

Note

⁽¹⁾ Available with: $dV/dt = 1000 V/\mu s$, to complete code add S90 i.e. 25RIA120S90

TRIGGERING					
PARAMETER	SYMBOL	TES	T CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}	T _J = T _J maximum		8.0	W
Maximum average gate power	P _{G(AV)}			2.0	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum		1.5	А
Maximum peak negative gate voltage	-V _{GM}	$T_J = T_J$ maximum		10	V
DC gate current required to trigger		T _J = - 65 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	90	mA
	I _{GT}	T _J = 25 °C		60	
		T _J = 125 °C		35	
	V _{GT}	T _J = - 65 °C		3.0	
DC gate voltage required to trigger		T _J = 25 °C		2.0	V
		T _J = 125 °C		1.0	
DC gate current not to trigger	I _{GD}	$T_J = T_J$ maximum, V_{DRM} = Rated value		2.0	mA
DC gate voltage not to trigger	V _{GD}	$T_J = T_J maximum,$ $V_{DRM} = Rated value$	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

25RIA Series

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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction and storage temperature range	T _J , T _{Stg}		- 65 to 125	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.75	- K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.35		
		Non-lubricated threads	3.4 ^{+ 0 - 10 %} (30)	N · m	
Allowable mounting torque		Lubricated threads	23 ^{+ 0 - 10 %} (20)	(lbf · in)	
Approvimete weight			14	g	
Approximate weight			0.49	oz.	
Case style See dimensions - link at th		See dimensions - link at the end of datasheet	TO-208AA (1	ГО-48)	

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.17	0.13					
120°	0.21	0.22					
90°	0.27	0.30	$T_J = T_J maximum$	K/W			
60°	0.40	0.42					
30°	0.69	0.70					

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

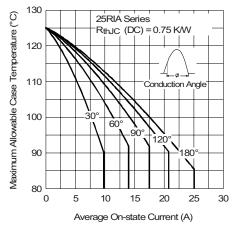


Fig. 1 - Current Ratings Characteristics

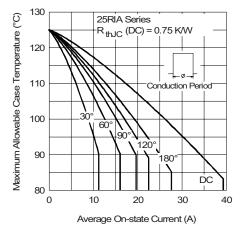


Fig. 2 - Current Ratings Characteristics

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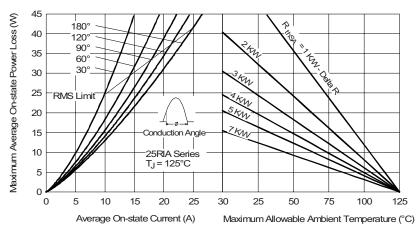


Fig. 3 - On-State Power Loss Characteristics

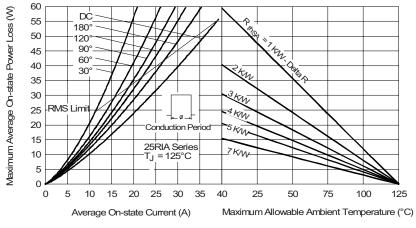


Fig. 4 - On-State Power Loss Characteristics

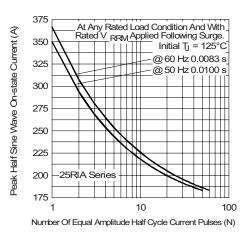


Fig. 5 - Maximum Non-Repetitive Surge Current

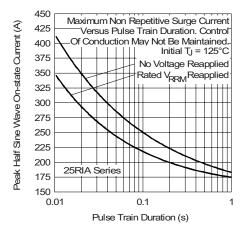


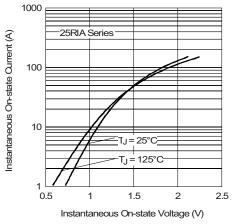
Fig. 6 - Maximum Non-Repetitive Surge Current

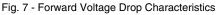
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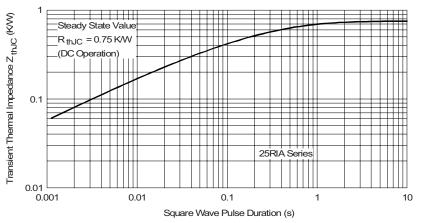
25RIA Series

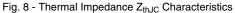
Vishay High Power Products Medium Power Thyristors

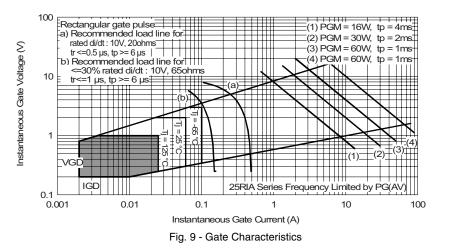
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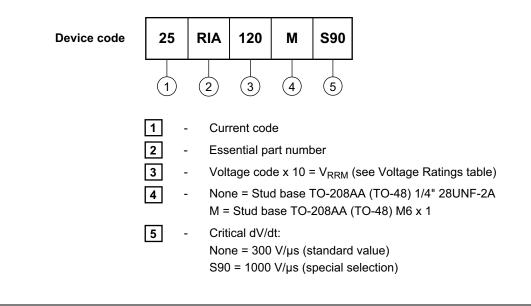


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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS		
Dimensions	http://www.vishay.com/doc?95333	



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